

P30B10EL

Power MOSFETs
100V, 30A, N-channel

Feature

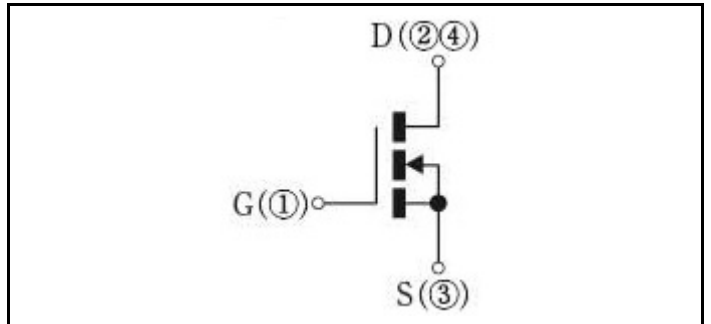
- N-channel
- SMD
- Low Ron
- 4.5V Gate Drive
- Low Capacitance
- Pb free terminal
- RoHS:Yes

OUTLINE

Package (House Name): FB
Package (JEDEC Code): TO-252AA



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	T _{stg}		-55 to 150	°C
Channel temperature	T _{ch}		150	°C
Drain-source voltage	V _{DSS}		100	V
Gate-source voltage	V _{GSS}		±20	V
Continuous drain current(DC)	I _D		30	A
Continuous drain current(Peak)	I _{DP}	Pulse width 10μs, duty=1/100	90	A
Total power dissipation	P _T		44	W
Single avalanche current	I _{AS}	Starting T _{ch} =25°C T _{ch} ≤150°C	27	A
Single avalanche energy	E _{AS}	Starting T _{ch} =25°C T _{ch} ≤150°C	73	mJ

* :See the original Specifications

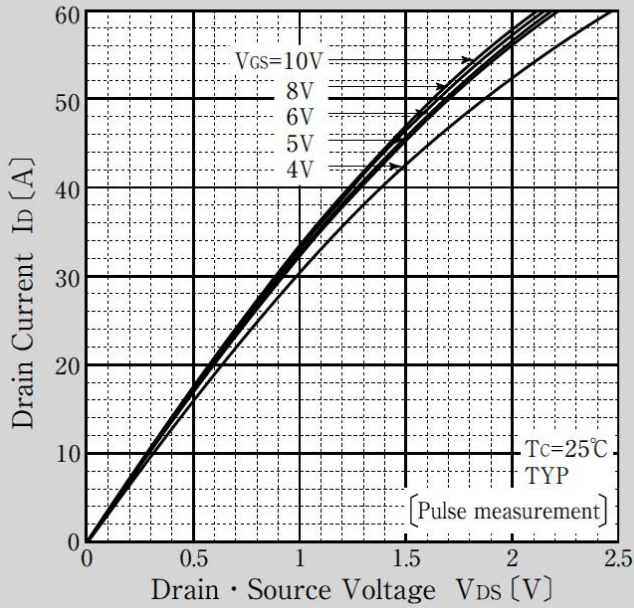
Electrical Characteristics (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	100			V
Zero gate voltage drain current	I_{DSS}	VDS=100V, VGS=0V			1	μA
Gate-source leakage current	I_{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g_{fs}	ID=15A, VDS=10V	12	24		S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=15A, VGS=10V		0.024	0.03	Ω
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=15A, VGS=4.5V		0.027	0.036	Ω
Gate threshold voltage	V_{th}	ID=1mA, VDS=10V	1.5	2	2.5	V
Source-drain diode forward voltage	V_{SD}	IS=30A, VGS=0V			1.5	V
Thermal resistance	$R_{th(j-c)}$	Junction to case			2.84	°C/W
Total gate charge	Q_g	VDD=80V, VGS=10V, ID=30A		37		nC
Gate to source charge	Q_{gs}	VDD=80V, VGS=10V, ID=30A		7		nC
Gate to drain charge	Q_{gd}	VDD=80V, VGS=10V, ID=30A		12		nC
Input capacitance	C_{iss}	VDS=25V, VGS=0V, f=1MHz		2000		pF
Reverse transfer capacitance	C_{rss}	VDS=25V, VGS=0V, f=1MHz		85		pF
Output capacitance	C_{oss}	VDS=25V, VGS=0V, f=1MHz		175		pF
Turn-on delay time	$t_{d(on)}$	ID=15A, RL=3.33Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		7		ns
Rise time	t_r	ID=15A, RL=3.33Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		16		ns
Turn-off delay time	$t_{d(off)}$	ID=15A, RL=3.33Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		20		ns
Fall time	t_f	ID=15A, RL=3.33Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		4		ns
Diode reverse recovery time	t_{rr}	IF=30A, VGS=0V, di/dt=100A/μs		57		ns
Diode reverse recovery charge	Q_{rr}	IF=30A, VGS=0V, di/dt=100A/μs		120		nC

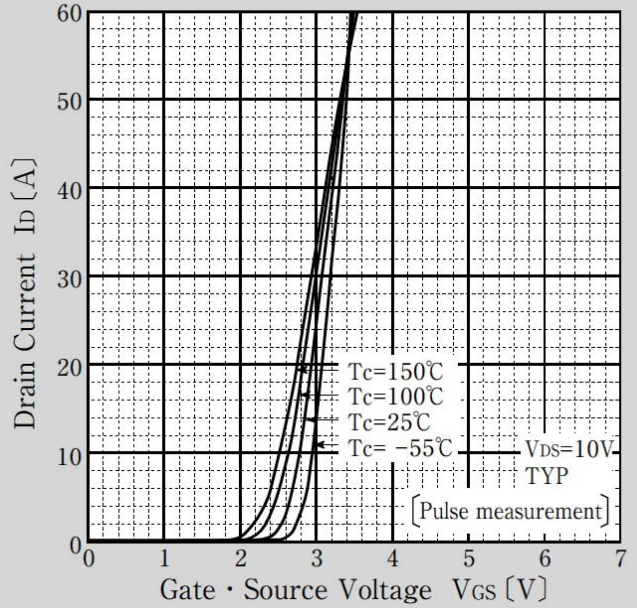
* : See the original Specifications

CHARACTERISTIC DIAGRAMS

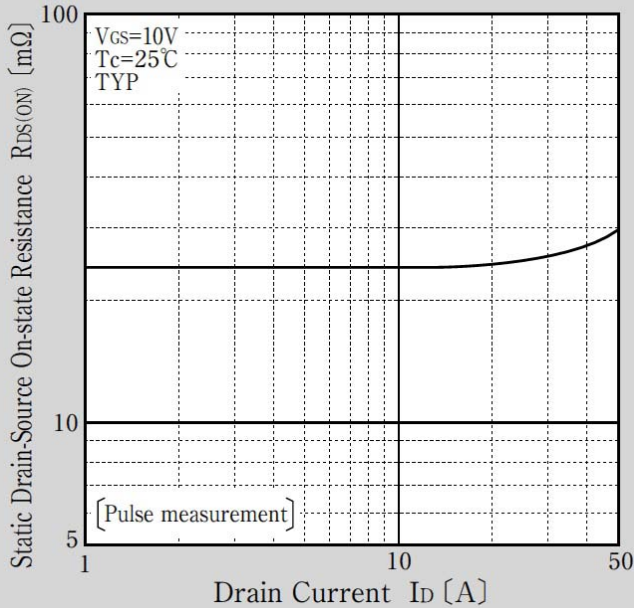
Typical Output Characteristics



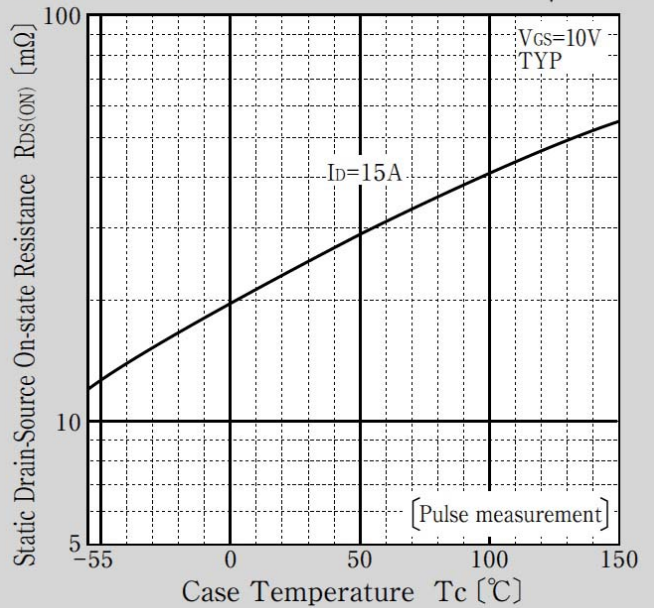
Transfer Characteristics



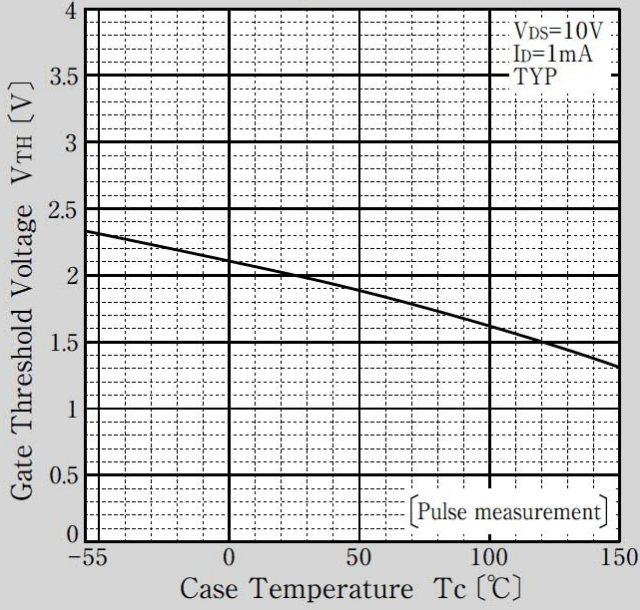
Static Drain-Source On-state Resistance vs Drain Current



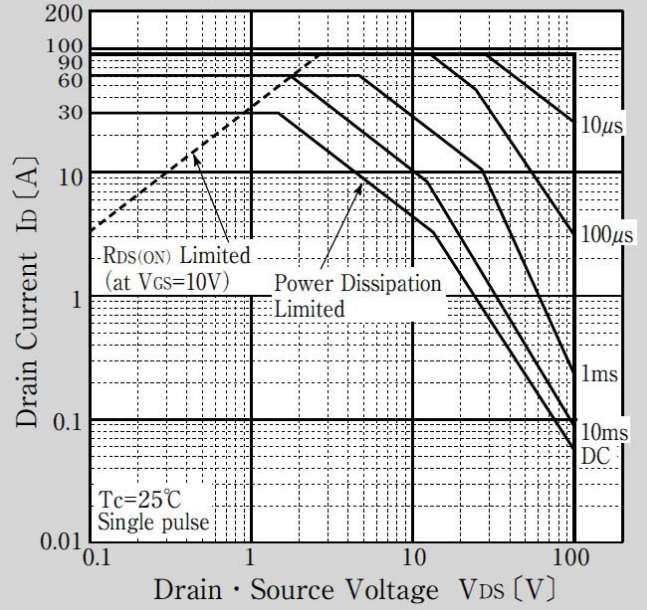
Static Drain-Source On-state Resistance vs Case Temperature



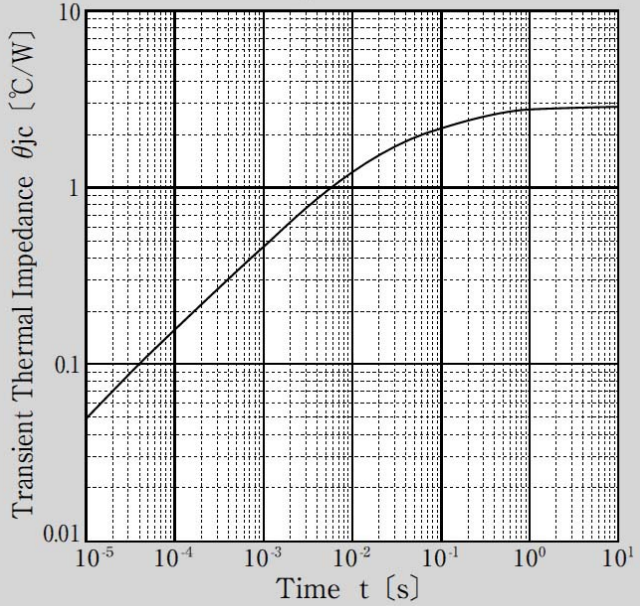
Gate Threshold Voltage vs Case Temperature



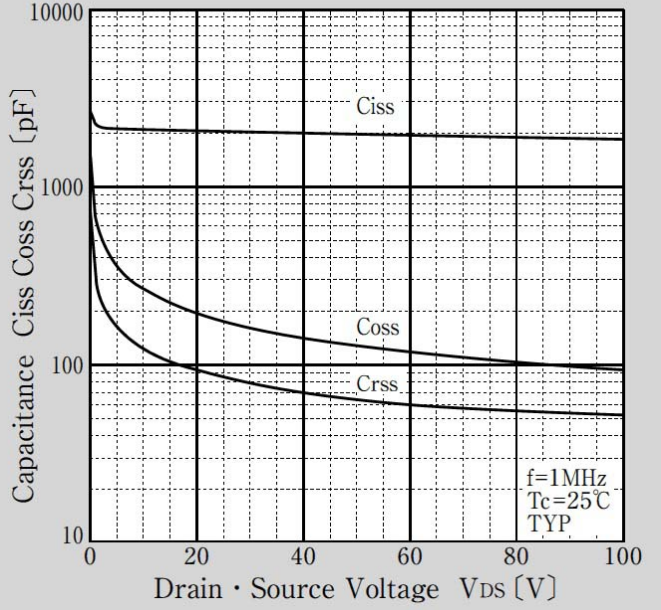
Safe Operating Area



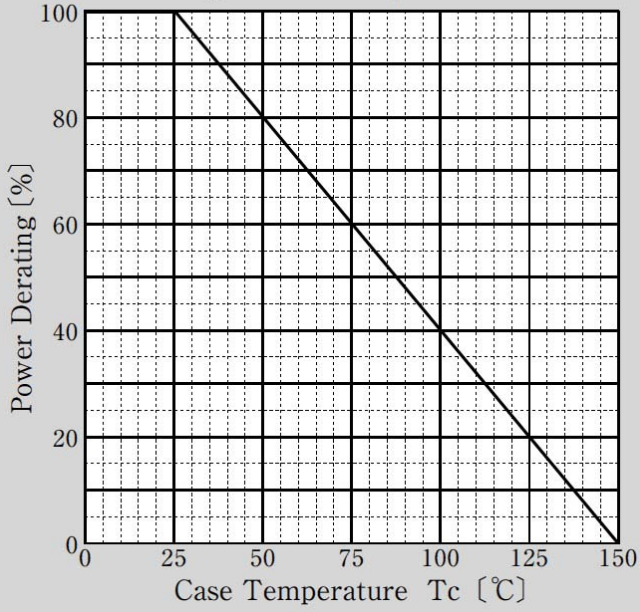
Transient Thermal Impedance



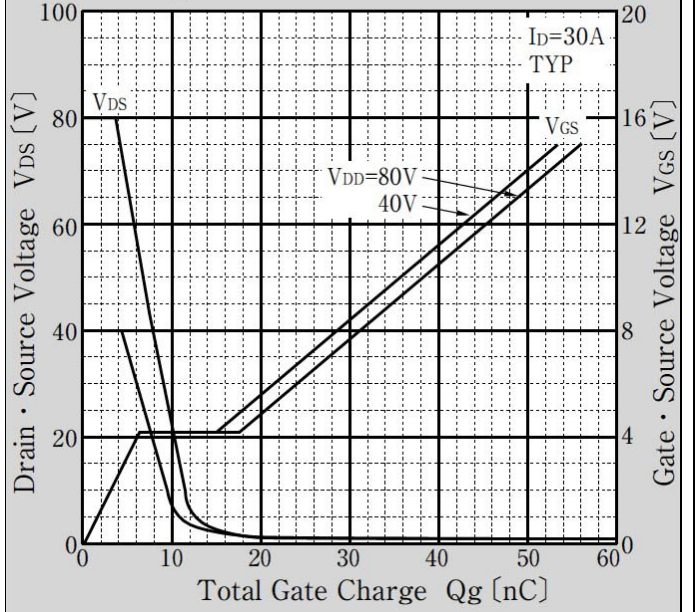
Capacitance Characteristics



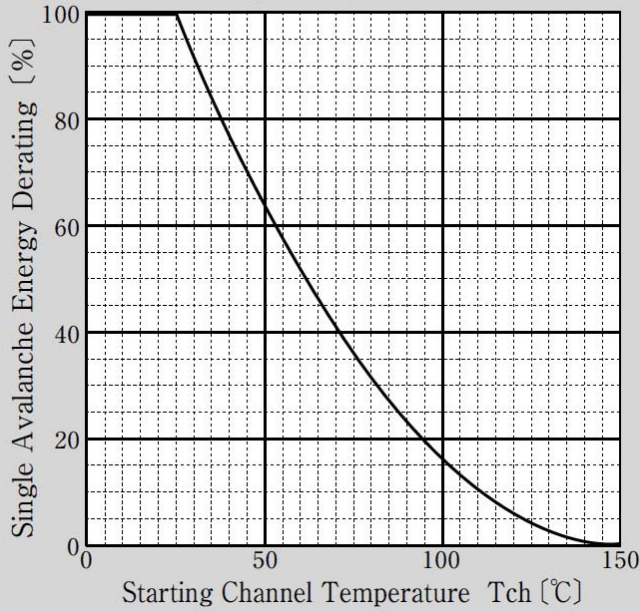
Power Derating - Case Temperature



Gate Charge Characteristics

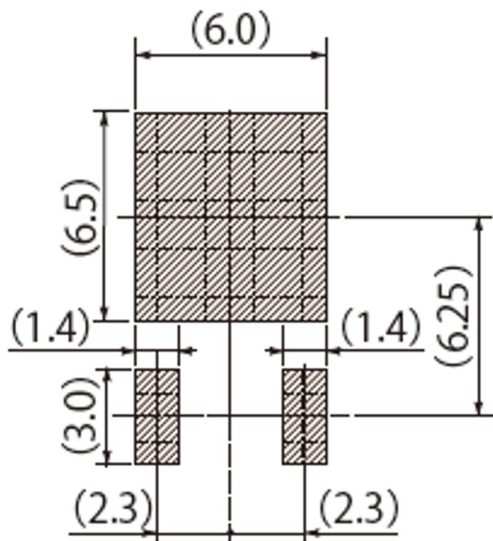
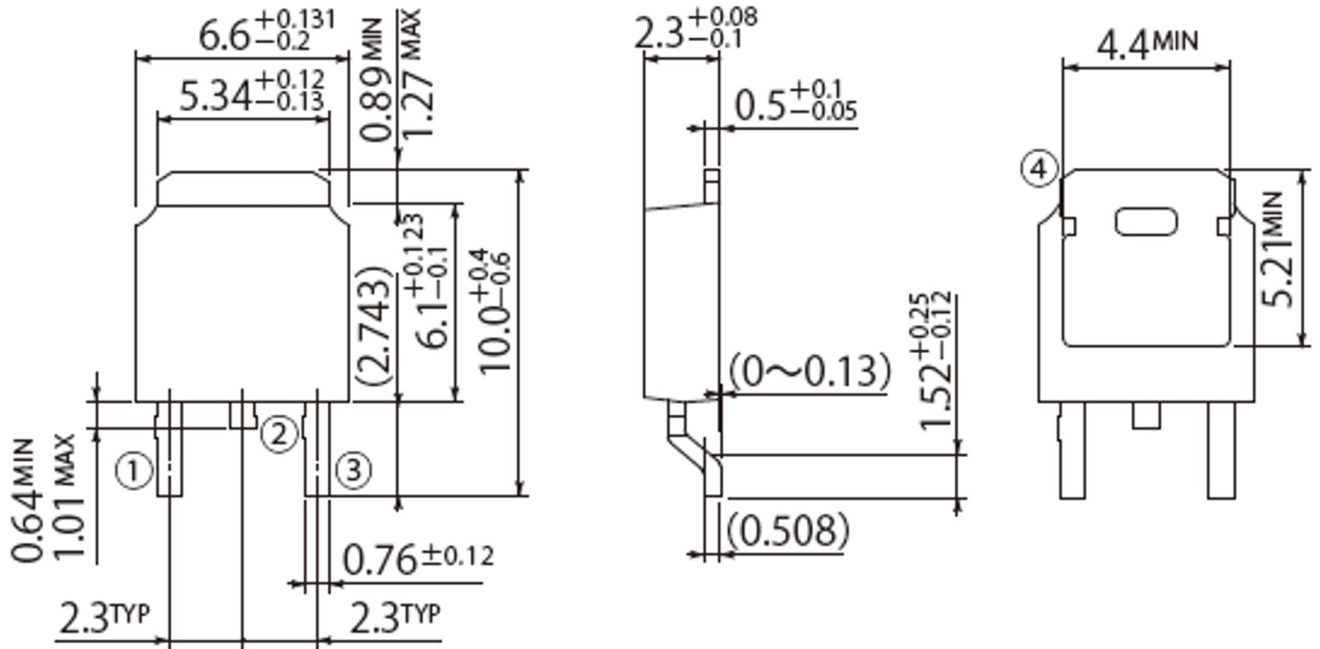


Single Avalanche Energy Derating vs Channel Temperature



G2

JEDEC Code	TO-252AA
JEITA Code	-
House Name	FB



Referential Soldering Pad

Notes

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